

FEATURES

- Upward compatible with the DS1643AL Timekeeping RAM to achieve higher RAM density
- Integrated NV SRAM, real time clock, crystal, power-fail control circuit and lithium energy source
- Low profile socketable module
 - 255 mil package height
- Clock registers are accessed identical to the static RAM. These registers are resident in the eight top RAM locations.
- Totally nonvolatile with over 10 years of operation in the absence of power
- Access time of 120 ns and 150 ns
- Quartz accuracy ± 1 minute a month @ 25°C, factory calibrated
- BCD coded year, month, date, day, hours, minutes, and seconds with leap year compensation valid up to 2100
- Power-fail write protection allows for $\pm 10\%$ V_{CC} power supply tolerance

ORDERING INFORMATION

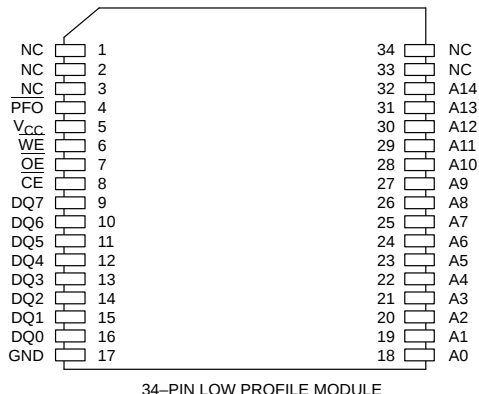
DS1644L-XXX Low Profile Module

└─	-120	120 ns access
	-150	150 ns access

DESCRIPTION

The DS1644L is a low profile module that requires a PLCC surface mountable socket and is functionally equivalent to the DS1644. The DS1644L is a 32K x 8 nonvolatile static RAM with a full function real time clock which are both accessible in a Byte-wide format. The real time clock information resides in the eight uppermost RAM locations. The RTC registers contain year, month, date, day, hours, minutes, and seconds data in 24 hour BCD format. Corrections for the day of the month and leap year are made automatically. The RTC clock registers are double buffered to avoid access of in-

PIN ASSIGNMENT



PIN DESCRIPTION

A0-A14	– Address Input
CE	– Chip Enable
OE	– Output Enable
WE	– Write Enable
V_{CC}	– +5 Volts
GND	– Ground
DQ0-DQ7	– Data Input/Output
NC	– No Connection
PFO	– Power Fail Output

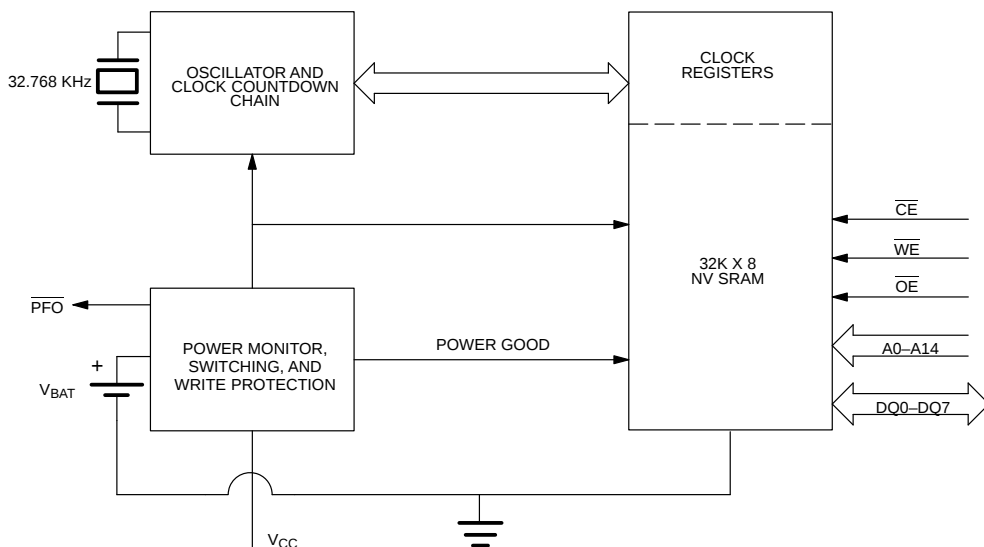
correct data that can occur during clock update cycles. The double buffered system also prevents time loss as the timekeeping countdown continues unabated by access to time register data. The DS1644L also contains its own power-fail circuitry which deselects the device when the V_{CC} supply is in an out-of-tolerance condition. This feature prevents loss of data from unpredictable system operation brought on by low V_{CC} as errant access and update cycles are avoided.

CLOCK OPERATIONS – READING THE CLOCK

While the double buffered register structure reduces the chance of reading incorrect data, internal updates to the DS1644L clock registers should be halted before clock data is read to prevent reading of data in transition. However, halting the internal clock register updating process does not affect clock accuracy. Updating is halted when a one is written into the read bit, the seventh most significant bit in the control register. As long as a

one remains in that position, updating is halted. After a halt is issued, the registers reflect the count, that is day, date, and time that was current at the moment the halt command was issued. However, the internal clock registers of the double buffered system continue to update so that the clock accuracy is not affected by the access of data. All of the DS1644L registers are updated simultaneously after the clock status is reset. Updating is within a second after the read bit is written to zero.

DS1644L BLOCK DIAGRAM Figure 1



DS1644L TRUTH TABLE Table 1

V _{CC}	$\overline{CE}$	$\overline{OE}$	$\overline{WE}$	MODE	DQ	POWER
5 VOLTS $\pm$ 10%	V _{IH}	X	X	DESELECT	HIGH-Z	STANDBY
	X	X	X	DESELECT	HIGH-Z	STANDBY
	V _{IL}	X	V _{IL}	WRITE	DATA IN	ACTIVE
	V _{IL}	V _{IL}	V _{IH}	READ	DATA OUT	ACTIVE
	V _{IL}	V _{IH}	V _{IH}	READ	HIGH-Z	ACTIVE
<4.5 VOLTS >V _{BAT}	X	X	X	DESELECT	HIGH-Z	CMOS STANDBY
<V _{BAT}	X	X	X	DESELECT	HIGH-Z	DATA RETENTION MODE

SETTING THE CLOCK

The eighth bit of the control register is the write bit. Setting the write bit to a one, like the read bit, halts updates to the DS1644L registers. The user can then load them with the correct day, date and time data in 24 hour BCD format. Resetting the write bit to a zero then transfers those values to the actual clock counters and allows normal operation to resume.

STOPPING AND STARTING THE CLOCK OSCILLATOR

The clock oscillator may be stopped at any time. To increase the shelf life, the oscillator can be turned off to minimize current drain from the battery. The $\overline{OSC}$ bit is the MSB for the seconds registers. Setting it to a one stops the oscillator.

FREQUENCY TEST BIT

Bit 6 of the day byte is the frequency test bit. When the frequency test bit is set to logic "1" and the oscillator is

running, the LSB of the seconds register will toggle at 512 Hz. When the seconds register is being read, the DQ0 line will toggle at the 512 Hz frequency as long as conditions for access remain valid (i.e., $\overline{CE}$ low, $\overline{OE}$ low, and address for seconds register remain valid and stable).

CLOCK ACCURACY

The DS1644L is guaranteed to keep time accuracy to within ± 1 minute per month at 25°C. The clock is calibrated at the factory by Dallas Semiconductor using special calibration nonvolatile tuning elements. The DS1644L does not require additional calibration, and temperature deviations will have a negligible effect in most applications. For this reason, methods of field clock calibration are not available and not necessary. Attempts to calibrate the clock that may be used with similar device types (MK48T08 family) will not have any effect even though the DS1644L appears to accept calibration data.

DS1644L REGISTER MAP – BANK1 Table 2

ADDRESS	DATA								FUNCTION
	B ₇	B ₆	B ₅	B ₄	B ₃	B ₂	B ₁	B ₀	
7FFF	–	–	–	–	–	–	–	–	YEAR 00–99
7FFE	X	X	X	–	–	–	–	–	MONTH 01–12
7FFD	X	X	–	–	–	–	–	–	DATE 01–31
7FFC	X	FT	X	X	X	–	–	–	DAY 01–07
7FFB	X	X	–	–	–	–	–	–	HOUR 00–23
7FFA	X	–	–	–	–	–	–	–	MINUTES 00–59
7FF9	OSC	–	–	–	–	–	–	–	SECONDS 00–59
7FF8	W	R	X	X	X	X	X	X	CONTROL A

OSC = STOP BIT
W = WRITE BIT

R = READ BIT
X = UNUSED

FT = FREQUENCY TEST

NOTE:
All indicated “X” bits are not dedicated to any particular function and can be used as normal RAM bits.

RETRIEVING DATA FROM RAM OR CLOCK
The DS1644L is in the read mode whenever $\overline{WE}$ (write enable) is high, and $\overline{CE}$ (chip enable) is low. The device architecture allows ripple-through access to any of the address locations in the NV SRAM. Valid data will be available at the DQ pins within t_{AA} after the last address input is stable, providing that the $\overline{CE}$ and $\overline{OE}$ access times and states are satisfied. If $\overline{CE}$ or $\overline{OE}$ access times are not met, valid data will be available at the latter of chip enable access (t_{CEA}) or at output enable access time (t_{OEA}). The state of the data input/output pins (DQ) is controlled by $\overline{CE}$ and $\overline{OE}$. If the outputs are activated before t_{AA} , the data lines are driven to an intermediate state until t_{AA} . If the address inputs are changed while $\overline{CE}$ and $\overline{OE}$ remain valid, output data will remain valid for output data hold time (t_{OH}) but will then go indeterminate until the next address access.

WRITING DATA TO RAM OR CLOCK
The DS1644L is in the write mode whenever $\overline{WE}$ and $\overline{CE}$ are in their active state. The start of a write is referenced to the latter occurring high to low transition of $\overline{WE}$ or $\overline{CE}$. The addresses must be held valid throughout the cycle. $\overline{CE}$ or $\overline{WE}$ must return inactive for a minimum of t_{WR} prior to the initiation of another read or write cycle. Data in must be valid t_{DS} prior to the end of write and remain valid for t_{DH} afterward. In a typical application, the $\overline{OE}$ signal will be high during a write cycle. However, $\overline{OE}$ can be active provided that care is taken with the data bus to avoid bus contention. If $\overline{OE}$ is low prior to $\overline{WE}$ transitioning low the data bus can become active with read data defined by the address inputs. A low transition on $\overline{WE}$ will then disable the outputs t_{WEZ} after $\overline{WE}$ goes active.

DATA RETENTION MODE

When V_{CC} is within nominal limits ($V_{CC} > 4.5$ volts) the DS1644L can be accessed as described above with read or write cycles. However, when V_{CC} is below the power fail point V_{PF} (point at which write protection occurs) the internal clock registers and RAM are blocked from access. This is accomplished internally by inhibiting access via the $\overline{CE}$ signal. At this time the power-fail output signal ($\overline{PFO}$) will be driven active low and will remain active until V_{CC} returns to nominal levels. When V_{CC} falls below the level of the internal battery supply, power input is switched from the V_{CC} pin to the internal battery and clock activity, RAM, and clock data are maintained from the battery until V_{CC} is returned to nominal level.

INTERNAL BATTERY LONGEVITY

The DS1644L has a self contained lithium power source that is designed to provide energy for clock activity, and

clock and RAM data retention when the V_{CC} supply is not present. The capability of this internal power supply is sufficient to power the DS1644L continuously for the life of the equipment in which it is installed. For specification purposes, the life expectancy is 10 years at 25°C with the internal clock oscillator running in the absence of V_{CC} power. The DS1644L is shipped from Dallas Semiconductor with the clock oscillator turned off, so the expected life should be considered to start from the time the clock oscillator is first turned on. Actual life expectancy of the DS1644L will be much longer than 10 years since no internal lithium battery energy is consumed when V_{CC} is present. In fact, in most applications, the life expectancy of the DS1644L will be approximately equal to the shelf life (expected useful life of the lithium battery with no load attached) of the lithium battery which may prove to be as long as 20 years.

ABSOLUTE MAXIMUM RATINGS*

Voltage on Any Pin Relative to Ground	−0.3V to +7.0V
Operating Temperature	0°C to 70°C
Storage Temperature	−20°C to +70°C
Soldering Temperature	260°C for 10 seconds (See Note 7)

* This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS (0°C to 70°C)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	V _{CC}	4.5	5.0	5.5	V	1
Logic 1 Voltage All Inputs	V _{IH}	2.2		V _{CC} +0.3	V	
Logic 0 Voltage All Inputs	V _{IL}	−0.3		0.8	V	

DC ELECTRICAL CHARACTERISTICS (0°C ≤ t_A ≤ 70°C; V_{CC}=5.0V ± 10%)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Average V _{CC} Power Supply Current	I _{CC1}			75	mA	3
TTL Standby Current ($\overline{CE} = V_{IH}$)	I _{CC2}			6	mA	3
CMOS Standby Current ($\overline{CE}=V_{CC}-0.2V$)	I _{CC3}			4.0	mA	3
Input Leakage Current (any input)	I _{IL}	−1		+1	μA	
Output Leakage Current	I _{OL}	−1		+1	μA	
Output Logic 1 Voltage (I _{OUT} = −1.0 mA)	V _{OH}	2.4			V	
Output Logic 0 Voltage (I _{OUT} = +2.1 mA)	V _{OL}			0.4	V	
Write Protection Voltage	V _{PF}	4.0	4.25	4.5	V	

AC ELECTRICAL CHARACTERISTICS(0°C to 70°C; $V_{CC} = 5.0V \pm 10\%$)

PARAMETER	SYMBOL	DS1644L-120		DS1644L-150		UNITS	NOTES
		MIN	MAX	MIN	MAX		
Read Cycle Time	t_{RC}	120		150		ns	
Address Access Time	t_{AA}		120		150	ns	
$\overline{CE}$ Access Time	t_{CEA}		120		150	ns	
$\overline{CE}$ Data Off Time	t_{CEZ}		40		50	ns	
Output Enable Access Time	t_{OEA}		100		120	ns	
Output Enable Data Off Time	t_{OEZ}		40		50	ns	
Output Enable to DQ Low-Z	t_{OEL}	5		5		ns	
$\overline{CE}$ to DQ Low-Z	t_{CEL}	5		5		ns	
Output Hold from Address	t_{OH}	5		5		ns	
Write Cycle Time	t_{WC}	120		150		ns	
Address Setup Time	t_{AS}	0		0		ns	
$\overline{CE}$ Pulse Width	t_{CEW}	100		120		ns	
Address Hold from End of Write	t_{AH1} t_{AH2}	5 30		5 30		ns ns	5 6
Write Pulse Width	t_{WEW}	120		150		ns	
$\overline{WE}$ Data Off Time	t_{WEZ}		40		50	ns	
$\overline{WE}$ or $\overline{CE}$ Inactive Time	t_{WR}	10		10		ns	
Data Setup Time	t_{DS}	85		110		ns	
Data Hold Time High	t_{DH1} t_{DH2}	0 25		0 25		ns ns	5 6

AC TEST CONDITIONS

Input Levels: 0V to 3V

Transition Times: 5 ns

CAPACITANCE(t_A = 25°C)

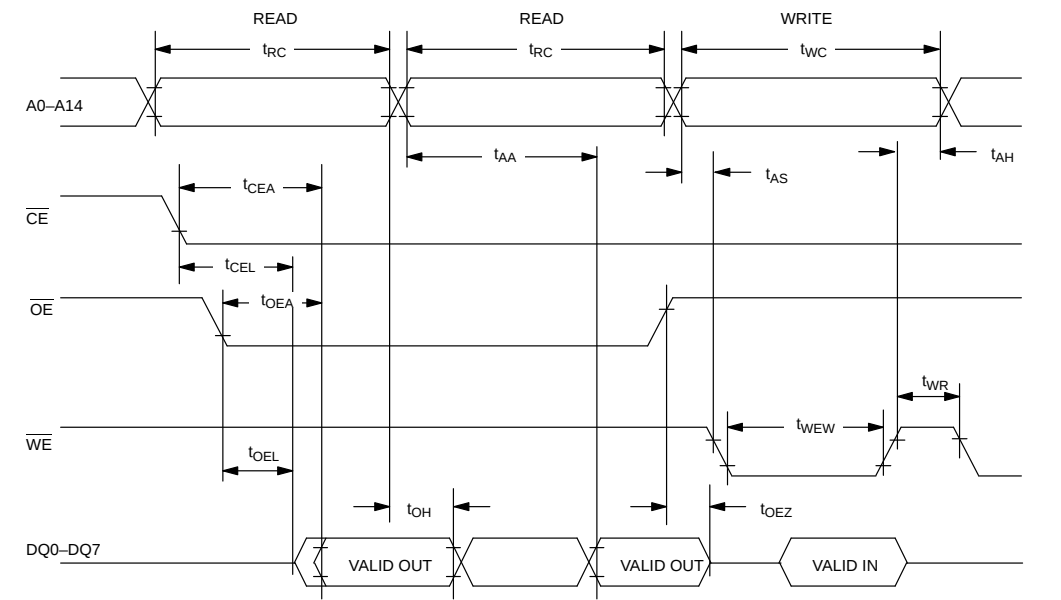
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Capacitance on all pins (except DQ)	C _I			7	pF	
Capacitance on DQ pins	C _{DQ}			10	pF	

AC ELECTRICAL CHARACTERISTICS (POWER-UP/DOWN TIMING)

(0°C to 70°C)

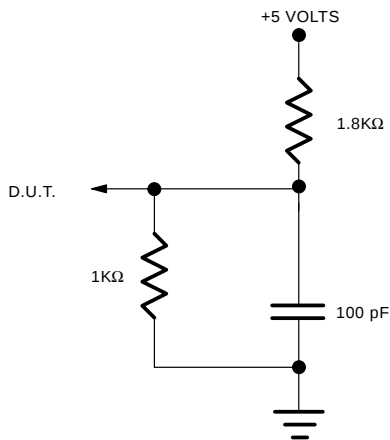
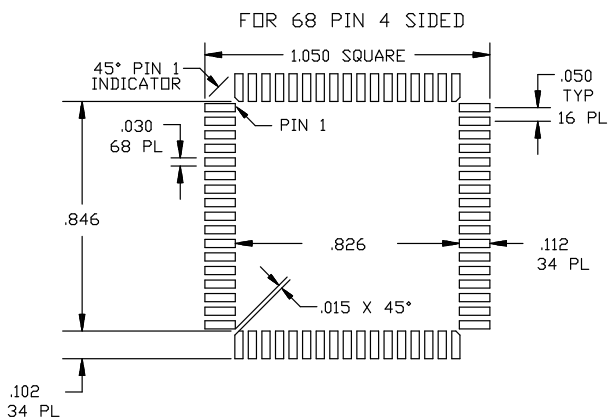
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
CE or WE at VIH before Power-Down	tPD	0			μs	
VPF (Max) to VPF (Min) VCC Fall Time	tF	300			μs	
VPF (Min) to VSO VCC Fall Time	tFB	10			μs	
VSO to VPF (Min) VCC Rise Time	tRB	1			μs	
VPF (Min) to VPF (Max) VCC Rise Time	tR	0			μs	
Power-Up	tREC	15	25	35	ms	
Expected Data Retention Time (Oscillator On)	tDR	10			years	4

DS1644L READ CYCLE TIMING

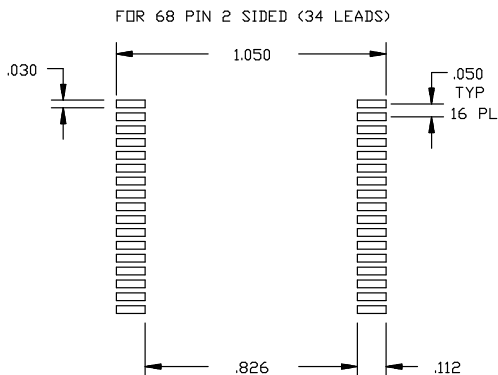


NOTES:

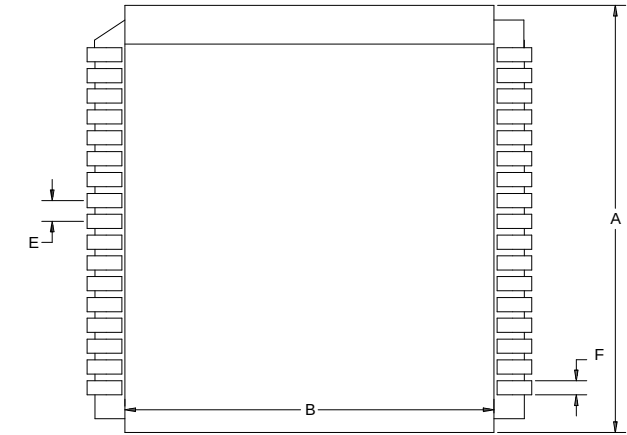
1. All voltages are referenced to ground.
2. Typical values are at 25°C and nominal supplies.
3. Outputs are open.
4. Data retention time is at 25°C and is calculated from the date code on the device package. The date code XXYY is the year followed by the week of the year in which the device was manufactured. For example, 9225, would mean the 25th week of 1992.
5. t_{AH1} , t_{DH1} are measured from $\overline{WE}$ going high.
6. t_{AH2} , t_{DH2} are measured from $\overline{CE}$ going high.
7. Unencapsulated Low Profile Modules are not recommended for processing through conventional wavesoldering techniques. The Use of a PLCC socket is recommended for production purposes.

OUTPUT LOAD**RECOMMENDED DS1644L MODULE SOCKET LAND PATTERNS**

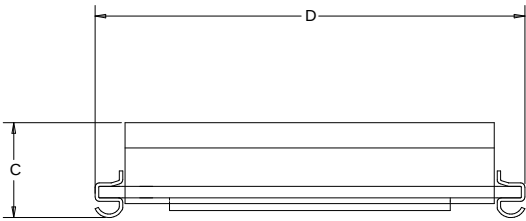
EITHER A TWO OR FOUR SIDED SOCKET MAY BE UTILIZED FOR DS1644LPM INSTALLATION.



DS1644LPM 34-PIN LOW PROFILE MODULE



PKG	INCHES	
	MIN	MAX
A	0.955	0.980
B	0.840	0.855
C	0.230	0.250
D	0.975	0.995
E	0.047	0.053
F	0.015	0.025



NOTE:
Please contact the factory for information on PLCC Surface mountable sockets.